

BIPOLAR ANALOG INTEGRATED CIRCUIT

μ PC4560

HIGH PERFORMANCE DUAL OPERATIONAL AMPLIFIER

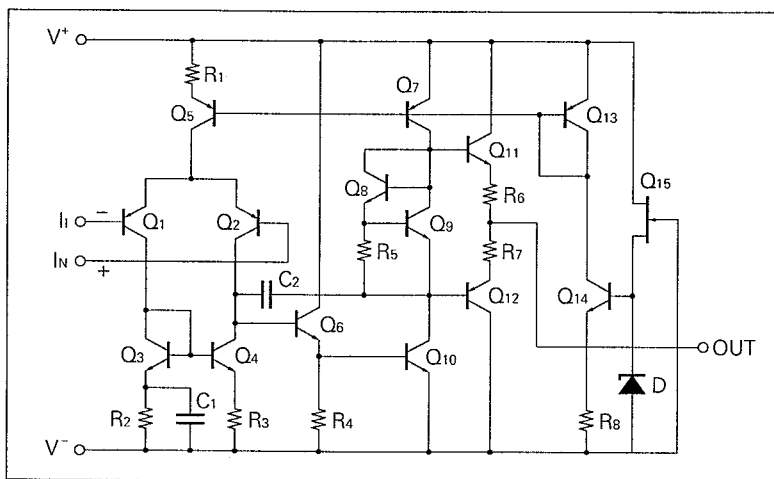
DESCRIPTION

The μ PC4560 is a dual operational amplifier which features more improved slew rate and G.B. products than that of μ PC4559 with unity gain frequency compensation. Also very low input noise and high output current drive capability make this device the optimum choice for audio applications and active filters.

FEATURES

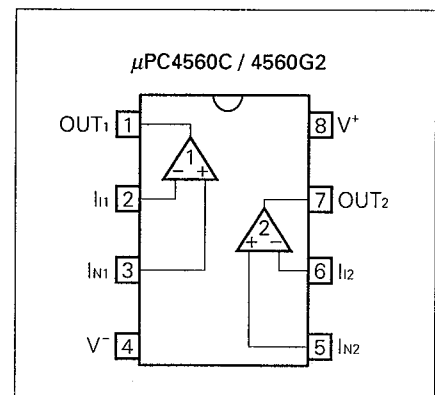
- Internal frequency compensation
- Gain bandwidth products: 10 MHz TYP.
- Low noise: 6 μ V_{p-p} TYP.
- High output current

EQUIVALENT CIRCUIT (1/2 Circuit)



CONNECTION DIAGRAM

(Top View)



ORDERING INFORMATION

PART NUMBER	PACKAGE	QUALITY GRADE
μ PC4560C	8 PIN PLASTIC DIP (300 mil)	Standard
μ PC4560G2	8 PIN PLASTIC SOP (225 mil)	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specifications of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25\text{ }^{\circ}\text{C}$)

PARAMETER		SYMBOL	μ PC4060	UNIT
Voltage between V^+ and V^- (Note 1)		$V^+ - V^-$	-0.3 to +36	V
Differential Input Voltage		V_{ID}	± 30	V
Input Voltage (Note 2)		V_I	$V^- - 0.3$ to $V^+ + 0.3$	V
Output Voltage (Note 3)		V_O	$V^- - 0.3$ to $V^+ + 0.3$	V
Power Dissipation	C Package (Note 4)	P_T	350	mW
	G2 Package (Note 5)		440	mW
Output Short Circuit Duration (Note 6)			0	sec
Operating Temperature Range		T_{opt}	-20 to +80	$^{\circ}\text{C}$
Storage Temperature Range		T_{stg}	-55 to +125	$^{\circ}\text{C}$

Note 1. Reverse connection of supply voltage can cause destruction.

Note 2. The input voltage should be allowed to input without damage or destruction. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The normal operation will establish when the both inputs are within the Common Mode Input Voltage Range of electrical characteristics.

Note 3. This specification is the voltage which should be allowed to supply to the output terminal from external without damage or destructive. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The output voltage of normal operation will be the Output Voltage Swing of electrical characteristics.

Note 4. Thermal derating factor is $-7.0\text{ mW} / ^{\circ}\text{C}$ when ambient temperature is higher than $55\text{ }^{\circ}\text{C}$.

Note 5. Thermal derating factor is $-4.4\text{ mW} / ^{\circ}\text{C}$ when ambient temperature is higher than $25\text{ }^{\circ}\text{C}$.

Note 6. Must not short to GND, V^+ , V^- , and other Voltage source. Pay careful attention to the total power dissipation not to exceed the absolute maximum ratings, Note 4 and Note 5.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	$V^{\pm}$	± 4		± 16	V

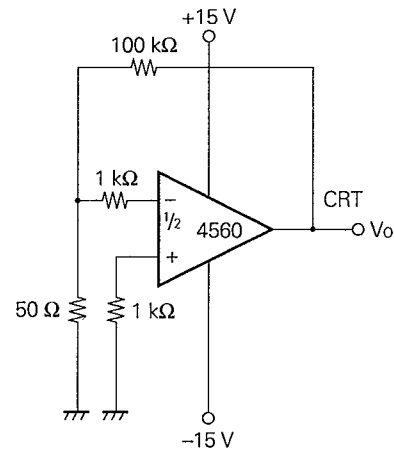
ELECTRICAL CHARACTERISTICS ($T_a = 25\text{ }^{\circ}\text{C}$, $V^{\pm} = \pm 15\text{ V}$)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Input Offset Voltage	V_{IO}		± 0.5	± 6.0	mV	$R_s \leq 10\text{ k}\Omega$
Input Offset Current (Note 7)	I_{IO}		± 5	± 200	nA	
Input Bias Current (Note 7)	I_B		60	500	nA	
Large Signal Voltage Gain	A_v	20000	180000			$R_L \geq 2\text{ k}\Omega$, $V_O = \pm 10\text{ V}$
Power Consumption	P_d		120	170	mW	$I_O = 0\text{ A}$, Both Amplifiers
Common Mode Rejection Ratio	CMR	70	100		dB	$R_s \leq 10\text{ k}\Omega$
Supply Voltage Rejection Ratio	SVR		10	150	$\mu\text{V/V}$	$R_s \leq 10\text{ k}\Omega$
Output Voltage Swing	V_{om}	± 12	± 14		V	$R_L \geq 2\text{ k}\Omega$
		± 10	± 13		V	$I_O = \pm 25\text{ mA}$
Common Mode Input Voltage Range	V_{ICM}	± 12	± 14		V	
Slew Rate	SR		2.8		V/ μs	$A_v = 1$
Input Equivalent Noise Voltage	V_n		6		$\mu\text{Vp-p}$	$R_s = 1\text{ k}\Omega$, $f = 1\text{ Hz}$ to 1 kHz (Fig.1)
Channel Separation			105		dB	$f = 1\text{ kHz}$ (Fig.2)

Note 7. Input bias currents flow out from IC. Because each currents are base current of PNP-transistor on input stage.

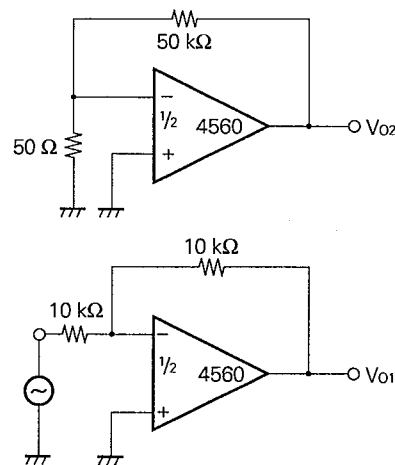
MEASUREMENT CIRCUIT

Fig. 1 Noise Measurement Circuit



$$V_n = \frac{V_o}{2000}$$

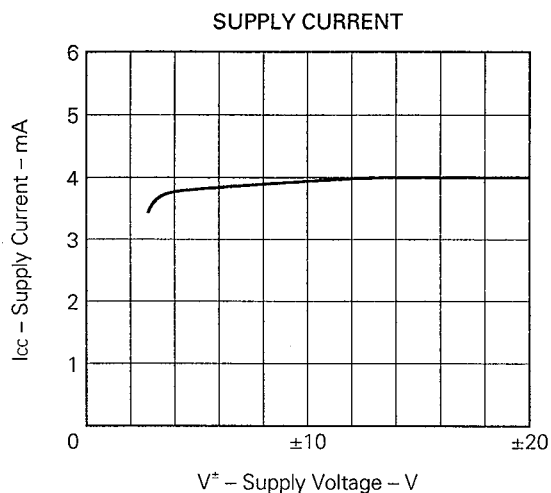
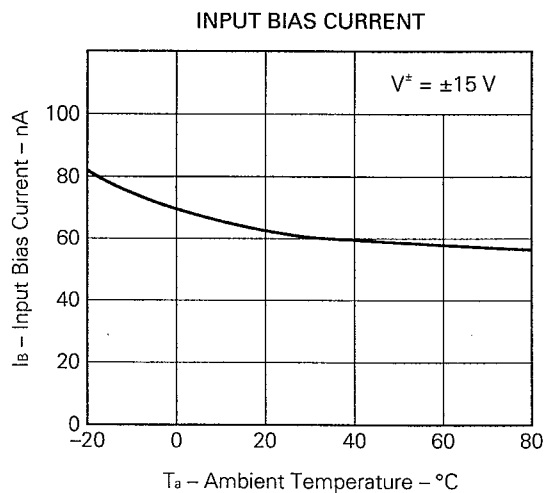
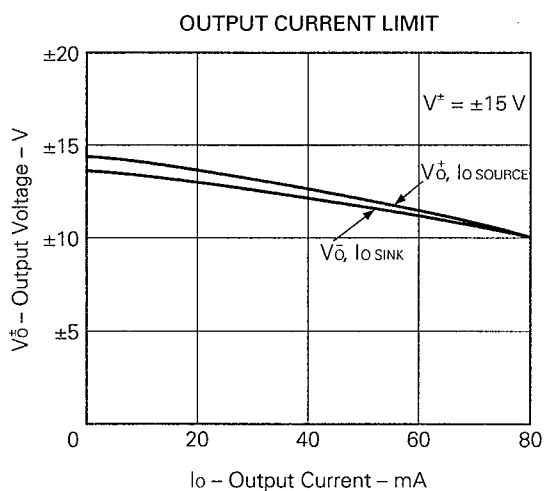
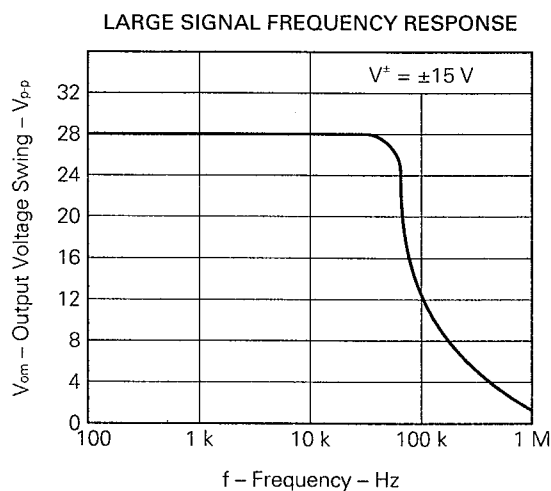
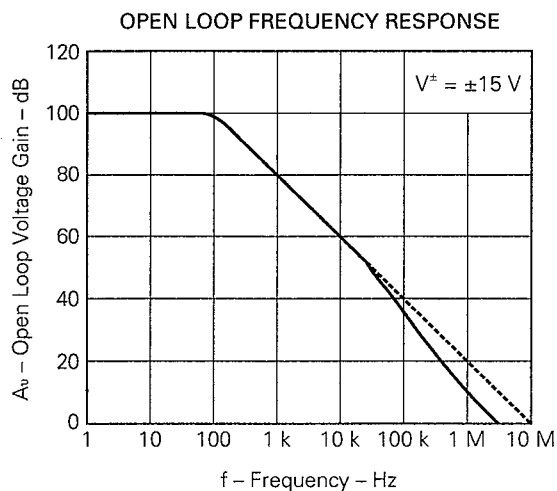
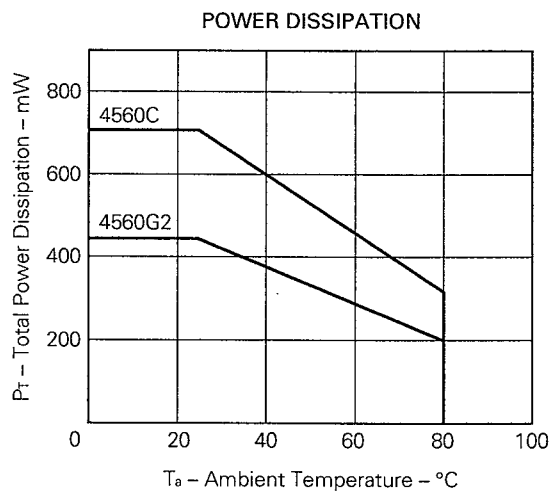
Fig. 2 Channel Separation Measurement Circuit



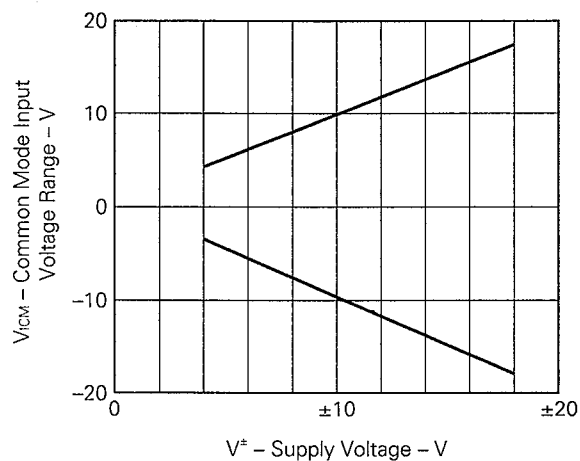
Channel separation

$$= \left| 20 \cdot \log \left(\frac{1}{1000} \cdot \frac{V_{o2}}{V_{o1}} \right) \right|$$

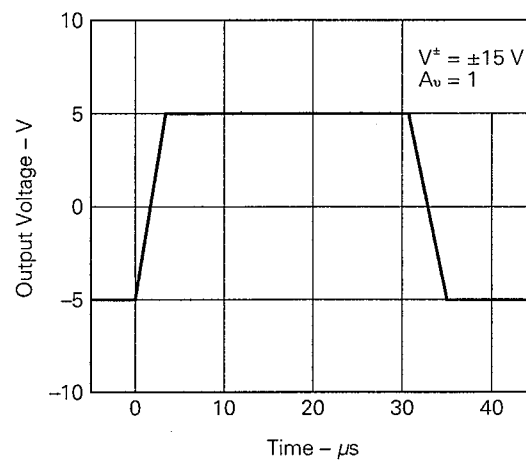
TYPICAL PERFORMANCE CHARACTERISTICS ($T_a = 25^\circ\text{C}$, TYP.)



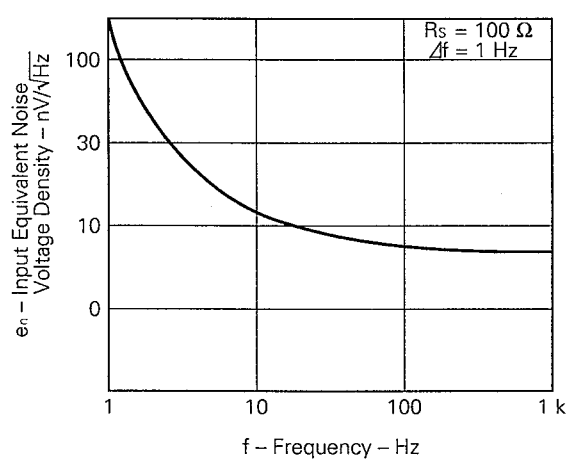
COMMON MODE INPUT VOLTAGE RANGE



PULSE RESPONSE

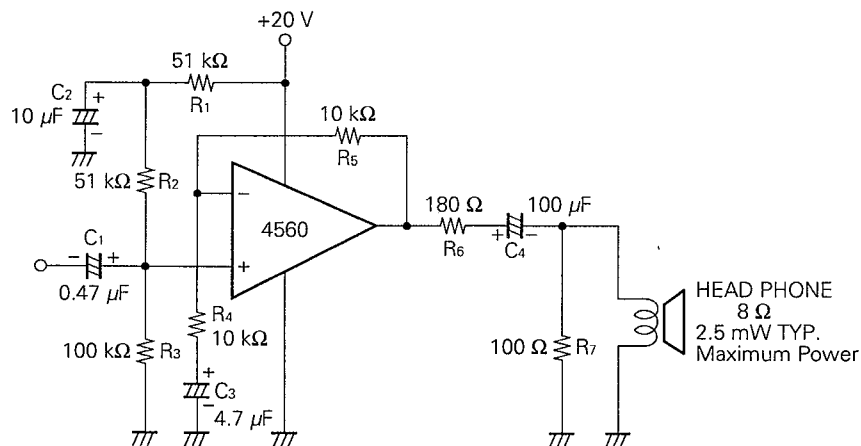


INPUT EQUIVALENT NOISE VOLTAGE DENSITY

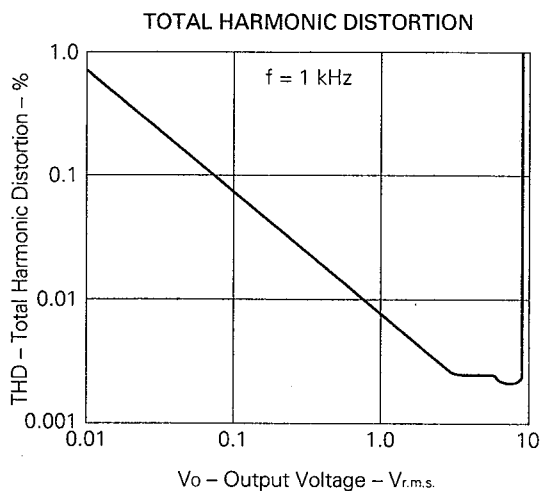
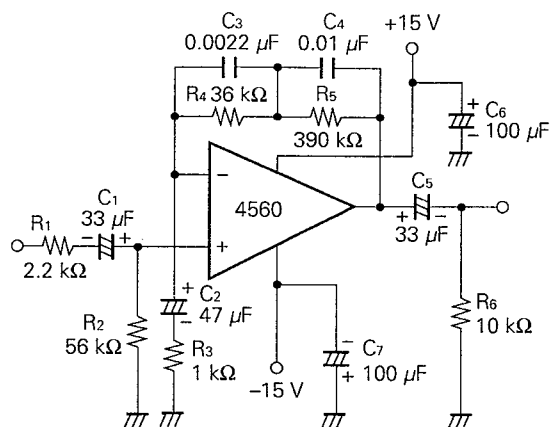


APPLICATION CIRCUITS

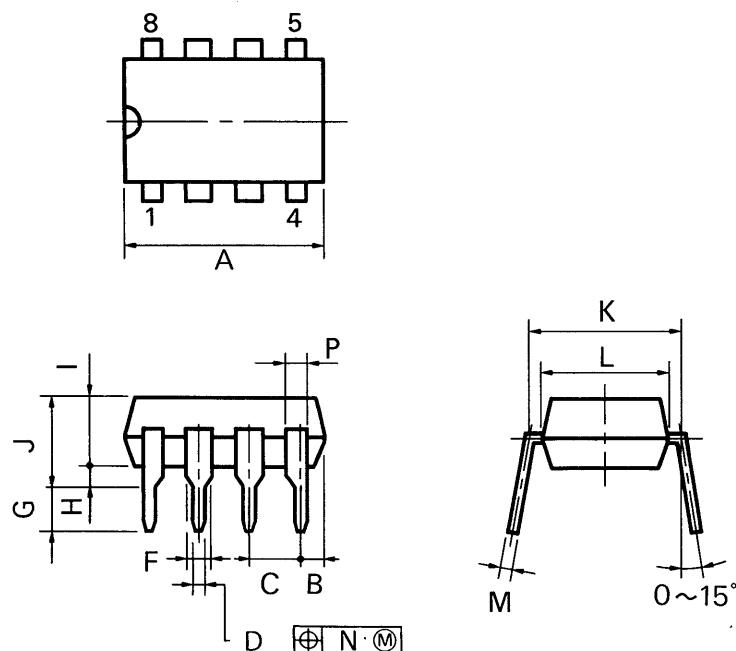
Head Phone Amp



RIAA Amp



8PIN PLASTIC DIP (300 mil)



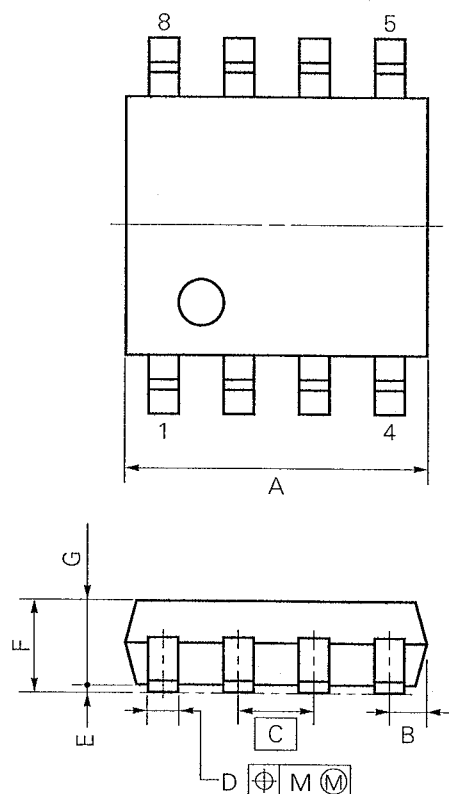
P8C-100-300B,C

NOTES

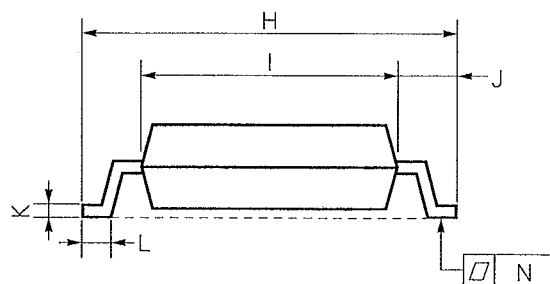
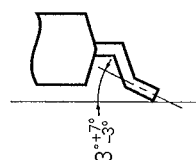
- Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
A	10.16 MAX.	0.400 MAX.
B	1.27 MAX.	0.050 MAX.
C	2.54 (T.P.)	0.100 (T.P.)
D	0.50 ± 0.10	0.020 ± 0.004
F	1.4 MIN.	0.055 MIN.
G	3.2 ± 0.3	0.126 ± 0.012
H	0.51 MIN.	0.020 MIN.
I	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
K	7.62 (T.P.)	0.300 (T.P.)
L	6.4	0.252
M	0.25 ± 0.10	0.010 ± 0.003
N	0.25	0.01
P	0.9 MIN.	0.035 MIN.

8 PIN PLASTIC SOP (225 mil)



detail of lead end



NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

S8GM-50-225B-2

ITEM	MILLIMETERS	INCHES
A	5.37 MAX.	0.212 MAX.
B	0.78 MAX.	0.031 MAX.
C	1.27 (T.P.)	0.050 (T.P.)
D	0.40 ^{+0.10} _{-0.05}	0.016 ^{+0.004} _{-0.003}
E	0.1±0.1	0.004±0.004
F	1.8 MAX.	0.071MAX.
G	1.49	0.059
H	6.5±0.3	0.256±0.012
I	4.4	0.173
J	1.1	0.043
K	0.15 ^{+0.10} _{-0.05}	0.006 ^{+0.004} _{-0.002}
L	0.6±0.2	0.024 ^{+0.008} _{-0.009}
M	0.12	0.005
N	0.15	0.006

RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

TYPES OF SURFACE MOUNT DEVICE

For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (IEI-1207).

[μPC4560G2]

Soldering method	Soldering conditions	Recommended condition symbol
Infrared ray reflow	Peak package's surface temperature: 230 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 1, Exposure limit*: None	IR30-00-1
VPS	Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 1, Exposure limit*: None	VP15-00-1
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below Number of flow process: 1, Exposure limit*: None	WS15-00-1
Partial heating method	Terminal temperature: 300 °C or below, Flow time: 10 seconds or below, Exposure limit*: None	

*: Exposure limit before soldering after dry-pack package is opened.
Storage conditions: 25 °C and relative humidity at 65 % or less.

Note: Do not apply more than a single process at once, except for "Partial heating method".

TYPES OF THROUGH HOLE DEVICE

[μPC4560C]

Soldering method	Soldering conditions	Recommended condition symbol
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below	

[MEMO]

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Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.



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- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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